INTEGRATED CIRCUITS

DATA SHEET

TEA1110A

Low voltage versatile telephone transmission circuit with dialler interface

Product specification Supersedes data of 1997 Apr 22 File under Integrated Circuits, IC03 2000 Feb 15





Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

FEATURES

- Low DC line voltage; operates down to 1.6 V (excluding voltage drop over external polarity guard)
- · Voltage regulator with adjustable DC voltage
- · Provides a supply for external circuits
- Symmetrical high impedance inputs (64 kΩ) for dynamic, magnetic or piezo-electric microphones
- Asymmetrical high impedance input (32 k Ω) for electret microphones
- DTMF input with confidence tone
- MUTE input for pulse or DTMF dialling
- Receiving amplifier for dynamic, magnetic or piezo-electric earpieces
- AGC line loss compensation for microphone and earpiece amplifiers.

APPLICATION

• Line powered telephone sets, cordless telephones, fax machines, answering machines.

GENERAL DESCRIPTION

The TEA1110A is a bipolar integrated circuit that performs all speech and line interface functions required in fully electronic telephone sets. It performs electronic switching between speech and dialling. The IC operates at a line voltage down to 1.6 V DC (with reduced performance) to facilitate the use of telephone sets connected in parallel.

All statements and values refer to all versions unless otherwise specified.

QUICK REFERENCE DATA

 I_{line} = 15 mA; V_{EE} = 0 V; R_{SLPE} = 20 Ω ; AGC pin connected to V_{EE} ; Z_{line} = 600 Ω ; f = 1 kHz; T_{amb} = 25 °C for TEA1110A(T); Tj = 25 °C for TEA1110AUH; unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--------------------|--|-------------------------------|------|------|------|------|
| I _{line} | line current operating range | normal operation | 11 | _ | 140 | mA |
| | | with reduced performance | 1 | _ | 11 | mA |
| V_{LN} | DC line voltage | | 3.35 | 3.65 | 3.95 | V |
| I _{CC} | internal current consumption | V _{CC} = 2.9 V | _ | 1.1 | 1.4 | mA |
| V _{CC} | supply voltage for peripherals | $I_P = 0 \text{ mA}$ | _ | 2.9 | _ | ٧ |
| G _{vtrx} | typical voltage gain microphone amplifier (not adjustable) | V _{MIC} = 4 mV (RMS) | _ | 43.7 | _ | dB |
| | receiving amplifier range | V _{IR} = 4 mV (RMS) | 19 | _ | 33 | dB |
| ΔG_{vtrx} | gain control range for microphone and receiving amplifiers with respect to $I_{\text{line}} = 15 \text{ mA}$ | I _{line} = 85 mA | _ | 5.9 | _ | dB |
| ΔG_{vtrxm} | gain reduction for microphone and receiving amplifiers | MUTE = LOW | _ | 80 | _ | dB |

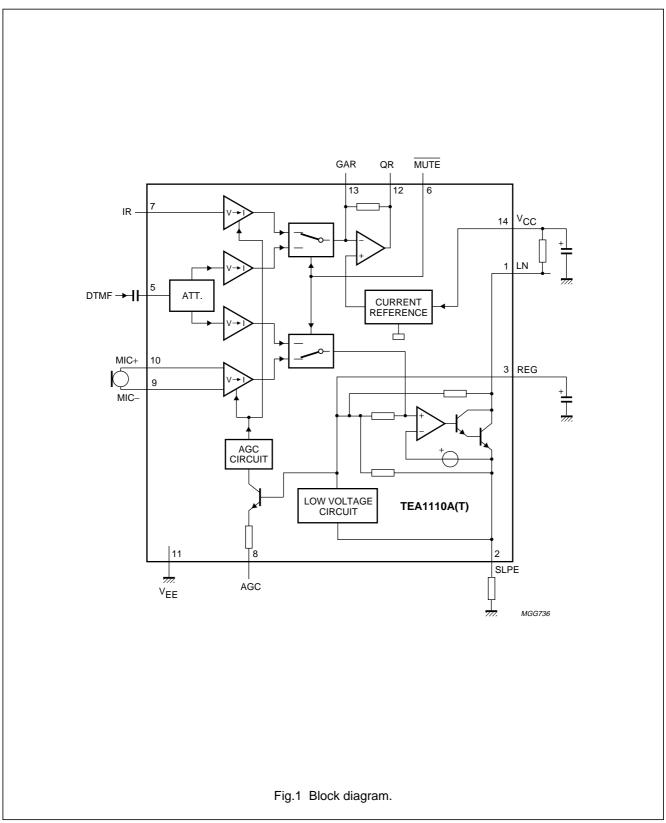
ORDERING INFORMATION

| TYPE | | PACKAGE | | |
|------------|-------------------------|--|----------|--|
| NUMBER | NUMBER NAME DESCRIPTION | | | |
| TEA1110A | DIP14 | plastic dual in-line package; 14 leads (300 mil) | SOT27-1 | |
| TEA1110AT | SO14 | plastic small outline package; 14 leads; body width 3.9 mm | SOT108-1 | |
| TEA1110AUH | _ | bare die; on foil | _ | |

Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

BLOCK DIAGRAM

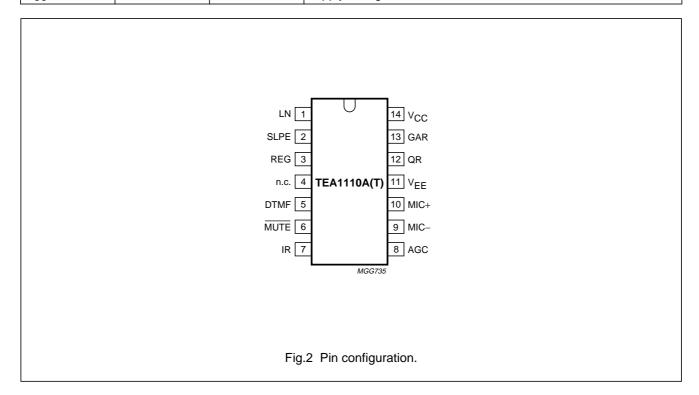


Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

PINNING

| SYMBOL | PIN | PAD | DESCRIPTION | | | |
|-----------------|-------------|------------|---|--|--|--|
| STIMBOL | TEA1110A(T) | TEA1110AUH | DESCRIPTION | | | |
| LN | 1 | 1 | positive line terminal | | | |
| SLPE | 2 | 2 | slope (DC resistance) adjustment | | | |
| REG | 3 | 3 | line voltage regulator decoupling | | | |
| n.c. | 4 | 4 | not connected | | | |
| DTMF | 5 | 5 | dual-tone multi-frequency input | | | |
| MUTE | 6 | 6 | mute input to select speech or dialling mode (active LOW) | | | |
| IR | 7 | 7 | receiving amplifier input | | | |
| AGC | 8 | 8 | automatic gain control/ line loss compensation | | | |
| MIC- | 9 | 9 | inverting microphone amplifier input | | | |
| MIC+ | 10 | 10 | non-inverting microphone amplifier input | | | |
| V _{EE} | 11 | 11 | negative line terminal | | | |
| QR | 12 | 12 | earpiece amplifier output | | | |
| GAR | 13 | 13 | earpiece amplifier gain adjustment | | | |
| V _{CC} | 14 | 14 | supply voltage for internal circuit | | | |



Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

FUNCTIONAL DESCRIPTION

All data given in this chapter are typical values, except when otherwise specified.

Supply (pins LN, SLPE, V_{CC} and REG)

The supply for the TEA1110A and its peripherals is obtained from the telephone line; see Fig.3.

The IC generates a stabilized reference voltage (V_{ref}) between pins LN and SLPE. V_{ref} is temperature compensated and can be adjusted by means of an external resistor (R_{VA}). V_{ref} equals 3.35 V and can be increased by connecting R_{VA} between pins REG and SLPE (see Fig.4), or decreased by connecting R_{VA} between pins REG and LN. The voltage at pin REG is used by the internal regulator to generate V_{ref} and is decoupled by C_{REG} , which is connected to V_{EE} . This capacitor, converted into an equivalent inductance (see Section "Set impedance"), realizes the set impedance conversion from its DC value (R_{SLPE}) to its AC value (R_{CC} in the audio-frequency range). The voltage at pin SLPE is proportional to the line current.

The voltage at pin LN is:

$$V_{LN} = V_{ref} + R_{SLPE} \times I_{SLPE}$$

$$I_{SLPE} = I_{line} - I_{CC} - I_{P} - I^*$$

Where:

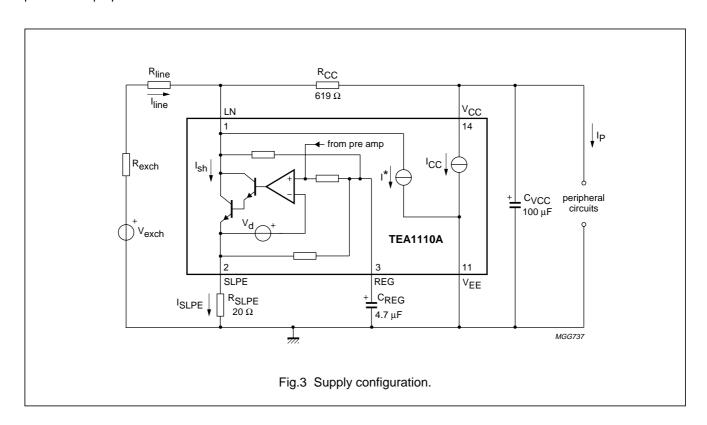
I_{line} = line current

 I_{CC} = current consumption of the IC

I_P = supply current for peripheral circuits

 I^* = current consumed between LN and V_{EE} .

The preferred value for R_{SLPE} is 20 $\Omega.$ Changing R_{SLPE} will affect more than the DC characteristics; it also influences the microphone and DTMF gains, the gain control characteristics, the sidetone level and the maximum output swing on the line.



Low voltage versatile telephone transmission circuit with dialler interface

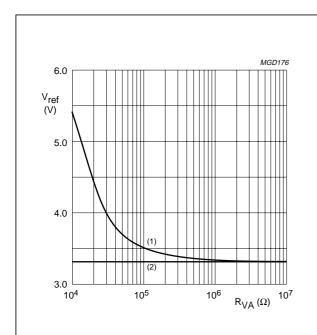
TEA1110A

The internal circuitry of the TEA1110A is supplied from pin $V_{CC}.$ This voltage supply is derived from the line voltage by means of a resistor (R $_{CC}$) and must be decoupled by a capacitor $C_{VCC}.$ It may also be used to supply peripheral circuits such as dialling or control circuits. The V_{CC} voltage depends on the current consumed by the IC and the peripheral circuits as shown by the formula: $V_{CC} = V_{CCO} - R_{CCint} \times (I_P - I_{rec})$

$$V_{CC0} = V_{LN} - R_{CC} \times I_{CC}$$
 (see also Figs 5 and 6).

R_{CCint} is the internal equivalent resistance of the voltage supply, and I_{rec} is the current consumed by the output stage of the earpiece amplifier.

The DC line current flowing into the set is determined by the exchange supply voltage (V_{exch}), the feeding bridge resistance (R_{exch}), the DC resistance of the telephone line (R_{line}) and the reference voltage (V_{ref}). With line currents below 7.5 mA, the internal reference voltage (generating V_{ref}) is automatically adjusted to a lower value. This means that more sets can operate in parallel with DC line voltages (excluding the polarity guard) down to an absolute minimum voltage of 1.6 V. At currents below 7.5 mA, the circuit has limited sending and receiving levels. This is called the low voltage area.



- (1) Influence of R_{VA} on V_{ref} .
- (2) V_{ref} without influence of R_{VA} .

Fig.4 Reference voltage adjustment by R_{VA}.

Set impedance

In the audio frequency range, the dynamic impedance is mainly determined by the R_{CC} resistor. The equivalent impedance of the circuit is illustrated in Fig.7.

Microphone amplifier (pins MIC+ and MIC-)

The TEA1110A has symmetrical microphone inputs. The input impedance between pins MIC+ and MIC– is 64 k Ω (2 × 32 k Ω). The voltage gain from pins MIC+/MIC– to pin LN is set at 43.7 dB (typ).

Automatic gain control is provided on this amplifier for line loss compensation.

Receiving amplifier (pins IR, GAR and QR)

The receiving amplifier has one input (IR) and one output (QR). The input impedance between pin IR and pin V_{EE} is 20 k Ω . The voltage gain from pin IR to pin QR is set at 33 dB (typ). The gain can be decreased by connecting an external resistor R_{GAR} between pins GAR and QR; the adjustment range is 14 dB. Two external capacitors C_{GAR} (connected between GAR and QR) and C_{GARS} (connected between GAR and V_{EE}) ensure stability. The C_{GAR} capacitor provides a first-order low-pass filter. The cut-off frequency corresponds to the time constant $C_{GAR} \times (R_{GARint} // R_{GAR})$. R_{GARint} is the internal resistor which sets the gain with a typical value of 125 k Ω . The condition $C_{GARS} = 10 \times C_{GAR}$ must be fulfilled to ensure stability.

The output voltage of the receiving amplifier is specified for continuous wave drive. The maximum output swing depends on the DC line voltage, the R_{CC} resistor, the I_{CC} current consumption of the circuit, the I_{P} current consumption of the peripheral circuits and the load impedance.

Automatic gain control is provided on this amplifier for line loss compensation.

Automatic gain control (pin AGC)

The TEA1110A performs automatic line loss compensation. The automatic gain control varies the gain of the microphone amplifier and the gain of the receiving amplifier in accordance with the DC line current. The control range is 5.9 dB (which corresponds approximately to a line length of 5 km for a 0.5 mm diameter twisted-pair copper cable with a DC resistance of 176 Ω /km and an average attenuation of 1.2 dB/km). The IC can be used with different configurations of feeding bridge (supply voltage and bridge resistance) by connecting an external resistor R_{AGC} between pins AGC and V_{EE} .

Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

This resistor enables the I_{start} and I_{stop} line currents to be increased (the ratio between I_{start} and I_{stop} is not affected by the resistor). The AGC function is disabled when pin AGC is left open-circuit.

Mute function (pin MUTE)

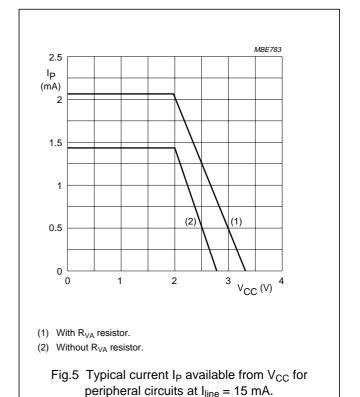
The mute function performs the switching between the speech mode and the dialling mode. When $\overline{\text{MUTE}}$ is LOW, the DTMF input is enabled and the microphone and receiving amplifiers inputs are disabled. When $\overline{\text{MUTE}}$ is HIGH, the microphone and receiving amplifiers inputs are enabled while the DTMF input is disabled. A pull-up resistor is included at the input.

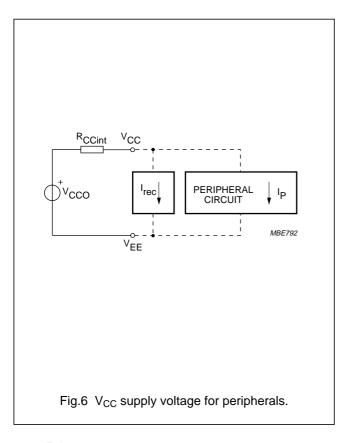
DTMF amplifier (pin DTMF)

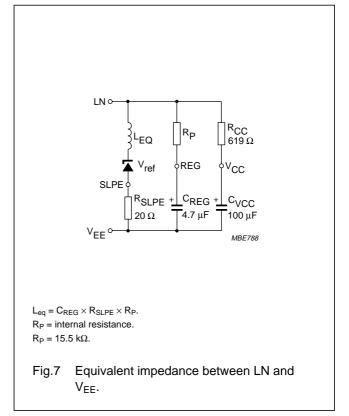
When the DTMF amplifier is enabled, dialling tones may be sent on line. These tones can be heard in the earpiece at a low level (confidence tone).

The TEA1110A has an asymmetrical DTMF input. The input impedance between DTMF and V_{EE} is 20 k Ω . The voltage gain from pin DTMF to pin LN is 25.3 dB.

The automatic gain control has no effect on the DTMF amplifier.







Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

SIDETONE SUPPRESSION

The TEA1110A anti-sidetone network comprising $R_{CC}//Z_{line}$, R_{ast1} , R_{ast2} , R_{ast3} , R_{SLPE} and Z_{bal} (see Fig.8) suppresses the transmitted signal in the earpiece. Maximum compensation is obtained when the following conditions are fulfilled:

$$R_{\text{SLPE}} \times R_{\text{ast1}} = R_{\text{CC}} \times (R_{\text{ast2}} + R_{\text{ast3}})$$

$$k = \frac{(R_{ast2} \times (R_{ast3} + R_{SLPE}))}{(R_{ast1} \times R_{SLPE})}$$

$$Z_{bal} = k \times Z_{line}$$

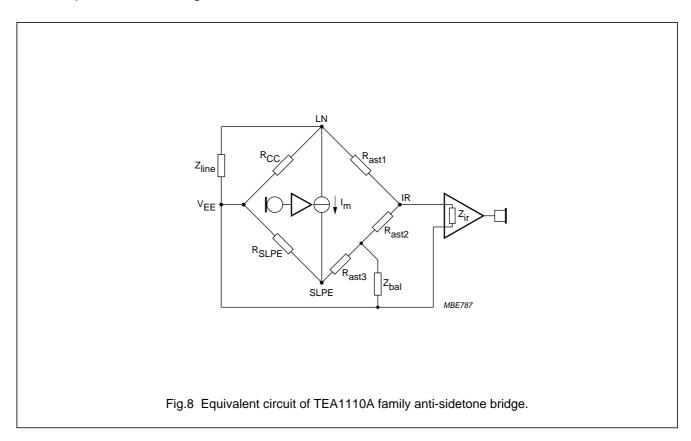
The scale factor k is chosen to meet the compatibility with a standard capacitor from the E6 or E12 range for Z_{bal} .

In practice, Z_{line} varies considerably with the line type and the line length. Therefore, the value of Z_{bal} should be for an average line length which gives satisfactory sidetone suppression with short and long lines. The suppression also depends on the accuracy of the match between Z_{bal} and the impedance of the average line.

The anti-sidetone network for the TEA1110A (as shown in Fig.13) attenuates the receiving signal from the line by 32 dB before it enters the receiving amplifier. The attenuation is almost constant over the whole audio frequency range.

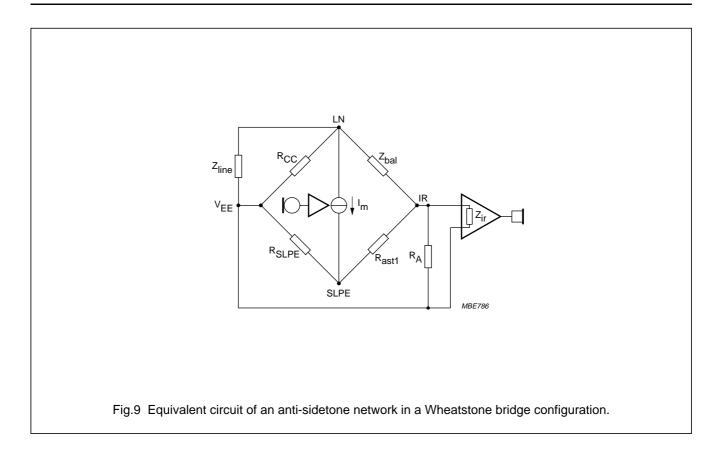
A Wheatstone bridge configuration (see Fig.9) may also be used.

More information on the balancing of an anti-sidetone bridge can be obtained in our publication "Applications Handbook for Wired Telecom Systems, IC03b", order number 9397 750 00811.



Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A



Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|---------------------|---|---|-----------------------|-----------------------|------|
| V _{LN} | positive continuous line voltage | | V _{EE} – 0.4 | 12 | V |
| | repetitive line voltage during switch-on or line interruption | | V _{EE} – 0.4 | 13.2 | V |
| V _{n(max)} | maximum voltage on all pins | | V _{EE} – 0.4 | V _{CC} + 0.4 | V |
| I _{line} | line current | $R_{SLPE} = 20 \Omega;$ see Figs 10 and 11 | _ | 140 | mA |
| P _{tot} | total power dissipation | T _{amb} = 75 °C; | | | |
| | TEA1110A | see Figs 10 and 11 | _ | 588 | mW |
| | TEA1110AT | | _ | 384 | mW |
| | TEA1110AUH; note 1 | | _ | _ | mW |
| T _{stg} | storage temperature | | -40 | +125 | °C |
| T _{amb} | operating ambient temperature | | -25 | +75 | °C |
| Tj | junction temperature | | _ | +125 | °C |

Note

1. Mostly dependent on the maximum required ambient temperature, on the voltage between LN and SLPE and on the thermal resistance between die ambient temperature. This thermal resistance depends on the application board layout and on the materials used. Figure 12 shows the safe operating area versus this thermal resistance for ambient temperature $T_{amb} = 75 \, ^{\circ}C$

HANDLING

This device meets class 2 ESD test requirements [Human Body Model (HBM)], in accordance with "MIL STD 883C - method 3015".

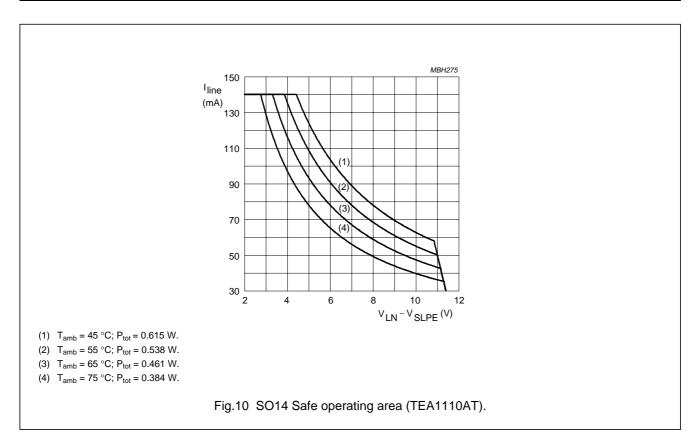
THERMAL CHARACTERISTICS

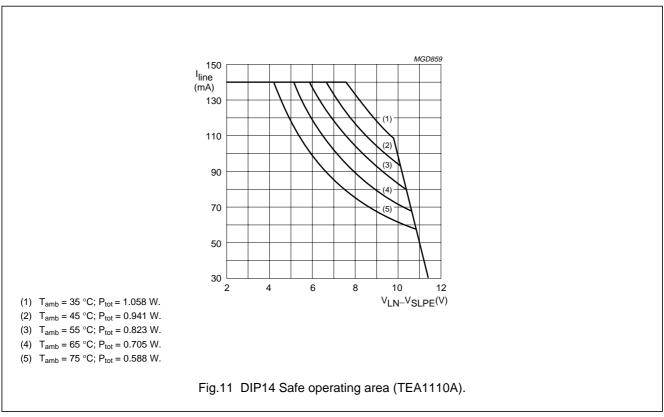
| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|--|-------------|------------------------------|-------------------|
| R _{th(j-a)} | thermal resistance from junction to ambient; mounted on epoxy board 40.1 × 19.1 × 1.5 mm TEA1110A TEA1110AUT TEA1110AUH | in free air | 85 130 tbf by customer | K/W K/W K/W |
| | | | in application | |

2000 Feb 15

Low voltage versatile telephone transmission circuit with dialler interface

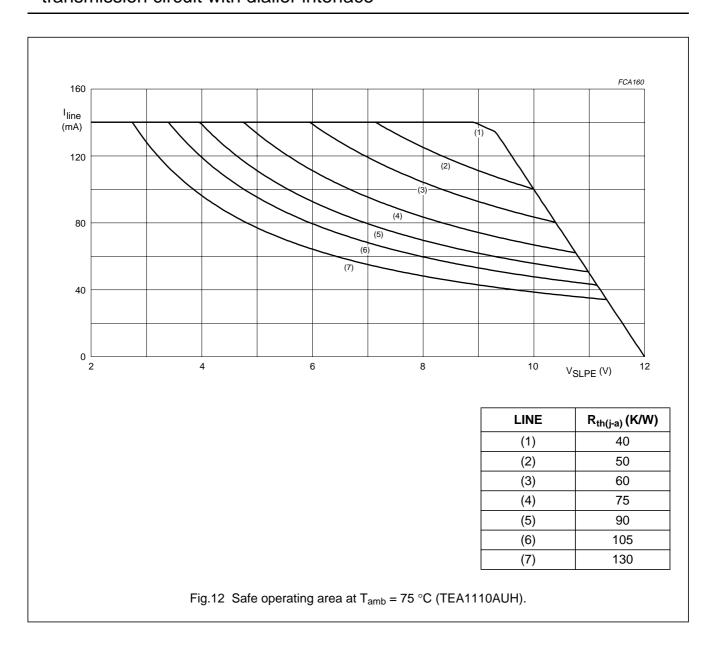
TEA1110A





Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A



Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

CHARACTERISTICS

 $I_{line} = 15 \text{ mA; } V_{EE} = 0 \text{ V; } R_{SLPE} = 20 \Omega; \text{ AGC pin connected to } V_{EE}; Z_{line} = 600 \Omega; \text{ f} = 1 \text{ kHz; } T_{amb} = 25 \text{ °C for TEA1110A(T); } T_j = 25 \text{ °C for TEA1110AUH; unless otherwise specified.}$

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------------------|---|--|------|-------|------|------|
| Supplies (pir | ns V _{LN} , V _{CC} , SLPE and REG) | 1 | | | | |
| V _{ref} | stabilized voltage between LN and SLPE | | 3.1 | 3.35 | 3.6 | V |
| V_{LN} | DC line voltage | I _{line} = 1 mA | - | 1.6 | _ | V |
| | | I _{line} = 4 mA | _ | 2.3 | _ | V |
| | | I _{line} = 15 mA | 3.35 | 3.65 | 3.95 | V |
| | | I _{line} = 140 mA | _ | _ | 6.9 | V |
| $V_{LN(exR)}$ | DC line voltage with an external resistor R _{VA} | $R_{VA(SLPE-REG)} = 27 \text{ k}\Omega$ | - | 4.4 | _ | V |
| $\Delta V_{LN(T)}$ | DC line voltage variation with temperature referred to 25 °C | $T_{amb} = -25 \text{ to } +75 ^{\circ}\text{C}$ | _ | ±30 | _ | mV |
| I _{CC} | internal current consumption | V _{CC} = 2.9 V | _ | 1.1 | 1.4 | mA |
| V _{CC} | supply voltage for peripherals | $I_P = 0 \text{ mA}$ | _ | 2.9 | _ | V |
| R _{CCint} | equivalent supply voltage resistance | I _P = 0.5 mA | _ | 550 | 620 | Ω |
| Microphone | amplifier (pins MIC+ and MIC-) | | | | | |
| Z _i | input impedance | | | | | |
| | differential between pins MIC+ and MIC- | | _ | 64 | _ | kΩ |
| | single-ended between pins MIC+/MIC- and V _{EE} | | - | 32 | _ | kΩ |
| G _{vtx} | voltage gain from MIC+/MIC- to LN | V _{MIC} = 4 mV (RMS) | 42.7 | 43.7 | 44.7 | dB |
| $\Delta G_{\text{vtx(f)}}$ | gain variation with frequency referred to 1 kHz | f = 300 to 3400 Hz | - | ±0.2 | _ | dB |
| $\Delta G_{\text{vtx}(T)}$ | gain variation with temperature referred to 25 °C | $T_{amb} = -25 \text{ to } +75 ^{\circ}\text{C}$ | - | ±0.3 | _ | dB |
| CMRR | common mode rejection ratio | | _ | 80 | _ | dB |
| V _{LN(max)(rms)} | maximum sending signal | I _{line} = 15 mA; THD = 2% | 1.4 | 1.7 | _ | V |
| | (RMS value) | I _{line} = 4 mA, THD = 10% | _ | 0.8 | _ | V |
| V _{notx} | noise output voltage at pin LN; pins MIC+/MIC- shorted through 200 Ω | psophometrically weighted (P53 curve) | _ | -78.5 | _ | dBmp |
| Receiving an | nplifier (pins IR, QR and GAR) | | | • | | ' |
| Z _i | input impedance | | _ | 20 | _ | kΩ |
| G _{vrx} | voltage gain from IR to QR | V _{IR} = 4 mV (RMS) | 32 | 33 | 34 | dB |
| $\Delta G_{\text{vrx(f)}}$ | gain variation with frequency referred to 1 kHz | f = 300 to 3400 Hz | - | ±0.2 | _ | dB |
| $\Delta G_{Vrx(T)}$ | gain variation with temperature referred to 25 °C | $T_{amb} = -25 \text{ to } +75 ^{\circ}\text{C}$ | - | ±0.3 | _ | dB |

Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|------------------------|--|--|-----------------------|------------|-----------------------|------|
| ΔG_{vrxr} | gain voltage reduction range | external resistor connected between GAR and QR | _ | _ | 14 | dB |
| V _{o(rms)} | maximum receiving signal (RMS value) | $I_P = 0$ mA sine wave drive; $R_L = 150 \Omega$; THD = 2% | _ | 0.25 | _ | V |
| | | $I_P = 0$ mA sine wave drive; $R_L = 450 \Omega$; THD = 2% | _ | 0.35 | _ | V |
| V _{norx(rms)} | noise output voltage at pin QR (RMS value) | G_{Vrx} = 33 dB; IR open-circuit; R_L = 150 Ω ; psophometrically weighted (P53 curve) | - | -87 | - | dBVp |
| Automatic ga | ain control (pin AGC) | • | 1 | | • | ' |
| ΔG_{vtrx} | gain control range for microphone and receiving amplifiers with respect to I _{line} = 15 mA | I _{line} = 85 mA | _ | 5.9 | _ | dB |
| I _{start} | highest line current for maximum gain | | _ | 23 | _ | mA |
| I _{stop} | lowest line current for minimum gain | | _ | 56 | _ | mA |
| DTMF amplif | ëer (pin DTMF) | | • | | | |
| Z _i | input impedance | | _ | 20 | _ | kΩ |
| G _{vdtmf} | voltage gain from DTMF to LN | V _{DTMF} = 20 mV (RMS); MUTE = LOW | 24.1 | 25.3 | 26.5 | dB |
| $\Delta G_{vdtmf(f)}$ | gain variation with frequency referred to 1 kHz | f = 300 to 3400 Hz | _ | ±0.2 | _ | dB |
| $\Delta G_{vdtmf(T)}$ | gain variation with temperature referred to 25 °C | $T_{amb} = -25 \text{ to } +75 ^{\circ}\text{C}$ | _ | ±0.4 | _ | dB |
| G _{vct} | voltage gain from DTMF to QR (confidence tone) | V_{DTMF} = 20 mV (RMS); R _L = 150 Ω | _ | –15 | - | dB |
| Mute functio | n (pin MUTE) | | | | | |
| V _{IL} | LOW level input voltage | | V _{EE} - 0.4 | _ | V _{EE} + 0.3 | V |
| V _{IH} | HIGH level input voltage | | V _{EE} + 1.5 | _ | $V_{CC} + 0.4$ | V |
| I _{MUTE} | input current | | _ | 1.5 | _ | μΑ |
| ΔG_{vtrxm} | gain reduction for microphone and receiving amplifiers | MUTE = LOW | _ | 80 | _ | dB |

Product specification

Philips Semiconductors

APPLICATION INFORMATION

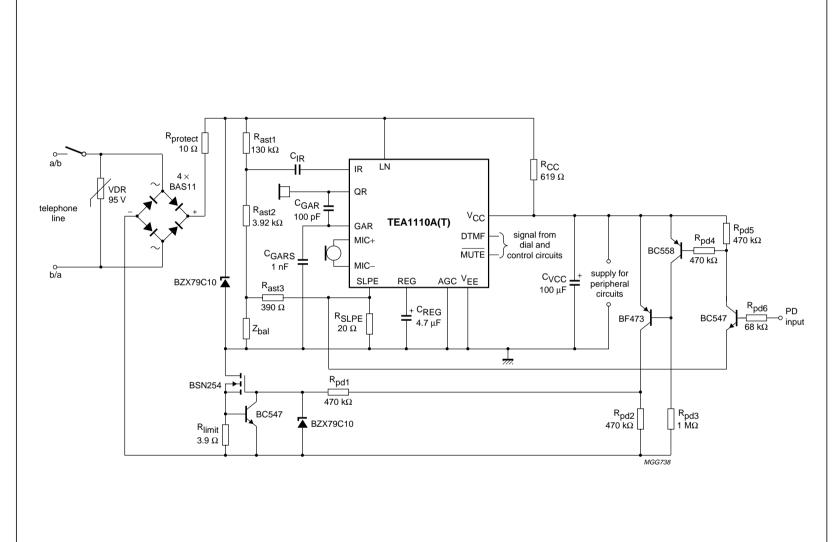


Fig.13 Typical application of the TEA1110A in sets with Pulse Dialling or Flash facilities.

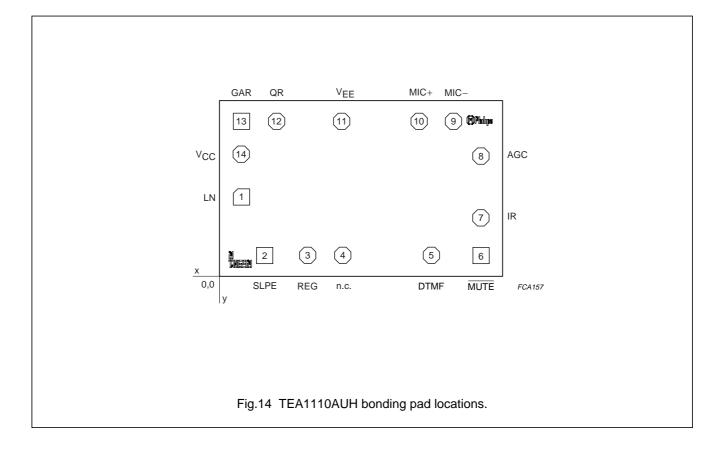
Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

BONDING PAD LOCATIONS FOR TEA1110AUH

All x/y coordinates represent the position of the centre of the pad (in μ m) with respect to the origin (x/y = 0/0) of the die (see Fig.14). The size of all pads is 80 μ m \times 80 μ m.

| SYMBOL | PAD | COORI | DINATES |
|-----------------|-----|--------|---------|
| STWIBOL | PAD | X | у |
| LN | 1 | 123 | 782 |
| SLPE | 2 | 251 | 459 |
| REG | 3 | 490.2 | 459 |
| n.c. | 4 | 685 | 459 |
| DTMF | 5 | 1174 | 459 |
| MUTE | 6 | 1450 | 459 |
| IR | 7 | 1449 | 664 |
| AGC | 8 | 1449.2 | 1006.8 |
| MIC- | 9 | 1297 | 1200 |
| MIC+ | 10 | 1108 | 1200 |
| V _{EE} | 11 | 678 | 1200 |
| QR | 12 | 318.2 | 1200.2 |
| GAR | 13 | 123 | 1201 |
| V _{CC} | 14 | 123 | 1017.8 |



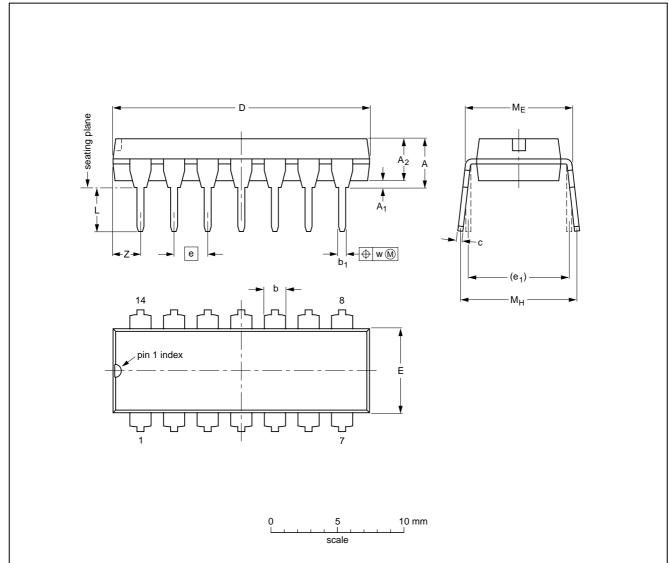
Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

PACKAGE OUTLINES

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

| UNIT | A max. | A ₁ min. | A ₂ max. | b | b ₁ | С | D ⁽¹⁾ | E (1) | e | e ₁ | L | ME | Мн | w | Z ⁽¹⁾ max. |
|--------|-----------|------------------------|------------------------|----------------|----------------|----------------|------------------|--------------|------|----------------|--------------|--------------|--------------|-------|--------------------------|
| mm | 4.2 | 0.51 | 3.2 | 1.73 1.13 | 0.53 0.38 | 0.36 0.23 | 19.50 18.55 | 6.48 6.20 | 2.54 | 7.62 | 3.60 3.05 | 8.25 7.80 | 10.0 8.3 | 0.254 | 2.2 |
| inches | 0.17 | 0.020 | 0.13 | 0.068 0.044 | 0.021 0.015 | 0.014 0.009 | 0.77 0.73 | 0.26 0.24 | 0.10 | 0.30 | 0.14 0.12 | 0.32 0.31 | 0.39 0.33 | 0.01 | 0.087 |

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

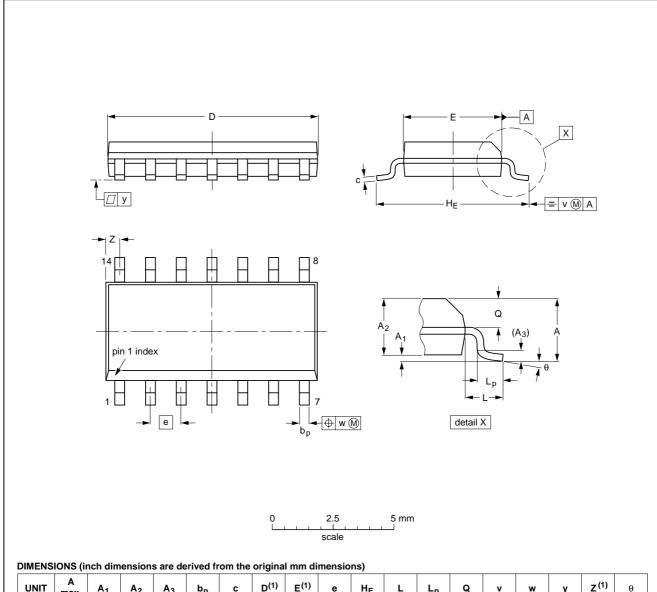
| OUTLINE | | REFER | ENCES | EUROPEAN | ISSUE DATE |
|---------|--------|--------|-----------|------------|---------------------------------|
| VERSION | IEC | JEDEC | EIAJ | PROJECTION | ISSUE DATE |
| SOT27-1 | 050G04 | MO-001 | SC-501-14 | | 95-03-11 99-12-27 |

Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



| UNIT | A max. | A ₁ | A ₂ | A ₃ | bp | С | D ⁽¹⁾ | E ⁽¹⁾ | е | HE | L | Lp | Q | v | w | у | z ⁽¹⁾ | θ |
|--------|-----------|----------------|----------------|----------------|--------------|------------------|------------------|------------------|-------|----------------|-------|----------------|----------------|------|------|-------|------------------|----|
| mm | 1.75 | 0.25 0.10 | 1.45 1.25 | 0.25 | 0.49 0.36 | 0.25 0.19 | 8.75 8.55 | 4.0 3.8 | 1.27 | 6.2 5.8 | 1.05 | 1.0 0.4 | 0.7 0.6 | 0.25 | 0.25 | 0.1 | 0.7 0.3 | 8° |
| inches | 0.069 | 0.010 0.004 | 0.057 0.049 | 0.01 | | 0.0100 0.0075 | 0.35 0.34 | 0.16 0.15 | 0.050 | 0.244 0.228 | 0.041 | 0.039 0.016 | 0.028 0.024 | 0.01 | 0.01 | 0.004 | 0.028 0.012 | 0° |

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

| OUTLINE | | REFER | ENCES | EUROPEAN | ISSUE DATE |
|----------|--------|--------|-------|------------|---------------------------------|
| VERSION | IEC | JEDEC | EIAJ | PROJECTION | ISSUE DATE |
| SOT108-1 | 076E06 | MS-012 | | | 97-05-22 99-12-27 |

Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

SOLDERING

Introduction

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our "Data Handbook IC26; Integrated Circuit Packages" (document order number 9398 652 90011).

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mount components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mount ICs, or for printed-circuit boards with high population densities. In these situations reflow soldering is often used.

Through-hole mount packages

SOLDERING BY DIPPING OR BY SOLDER WAVE

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joints for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ($T_{stg(max)}$). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

MANUAL SOLDERING

Apply the soldering iron (24 V or less) to the lead(s) of the package, either below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 $^{\circ}$ C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 $^{\circ}$ C, contact may be up to 5 seconds.

Surface mount packages

REFLOW SOLDERING

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, infrared/convection heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 $^{\circ}$ C. The top-surface temperature of the packages should preferable be kept below 230 $^{\circ}$ C.

WAVE SOLDERING

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is **preferred** to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

 For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C. A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

MANUAL SOLDERING

19

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C.

2000 Feb 15

Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

Suitability of IC packages for wave, reflow and dipping soldering methods

| MOUNTING | PACKAGE | SOLDERING METHOD | | |
|--------------------|---|-----------------------------------|-----------------------|----------|
| | | WAVE | REFLOW ⁽¹⁾ | DIPPING |
| Through-hole mount | DBS, DIP, HDIP, SDIP, SIL | suitable ⁽²⁾ | _ | suitable |
| Surface mount | BGA, LFBGA, SQFP, TFBGA | not suitable | suitable | _ |
| | HBCC, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, SMS | not suitable ⁽³⁾ | suitable | _ |
| | PLCC ⁽⁴⁾ , SO, SOJ | suitable | suitable | _ |
| | LQFP, QFP, TQFP | not recommended ⁽⁴⁾⁽⁵⁾ | suitable | _ |
| | SSOP, TSSOP, VSO | not recommended ⁽⁶⁾ | suitable | _ |

Notes

- 1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the "Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods".
- 2. For SDIP packages, the longitudinal axis must be parallel to the transport direction of the printed-circuit board.
- 3. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
- 4. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- 5. Wave soldering is only suitable for LQFP, QFP and TQFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- 6. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

DEFINITIONS

| Data sheet status | | | |
|---|---|--|--|
| Objective specification | This data sheet contains target or goal specifications for product development. | | |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published late | | |
| Product specification | This data sheet contains final product specifications. | | |
| Limiting values | | | |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | | | |
| Application information | | | |
| Where application informati | on is given, it is advisory and does not form part of the specification | | |

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

BARE DIE DISCLAIMER

All die are tested and are guaranteed to comply with all data sheet limits up to the point of wafer sawing for a period of ninety (90) days from the date of Philips' delivery. If there are data sheet limits not guaranteed, these will be separately indicated in the data sheet. There is no post waffle pack testing performed on individual die. Although the most modern processes are utilized for wafer sawing and die pick and place into waffle pack carriers, Philips Semiconductors has no control of third party procedures in the handling, packing or assembly of the die. Accordingly, Philips Semiconductors assumes no liability for device functionality or performance of the die or systems after handling, packing or assembly of the die. It is the responsibility of the customer to test and qualify their application in which the die is used.

Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

NOTES

Low voltage versatile telephone transmission circuit with dialler interface

TEA1110A

NOTES

Philips Semiconductors – a worldwide company

Argentina: see South America

Australia: 3 Figtree Drive, HOMEBUSH, NSW 2140, Tel. +61 2 9704 8141, Fax. +61 2 9704 8139 Austria: Computerstr. 6, A-1101 WIEN, P.O. Box 213, Tel. +43 1 60 101 1248. Fax. +43 1 60 101 1210

Belarus: Hotel Minsk Business Center, Bld. 3, r. 1211, Volodarski Str. 6,

220050 MINSK, Tel. +375 172 20 0733, Fax. +375 172 20 0773

Belgium: see The Netherlands Brazil: see South America

Bulgaria: Philips Bulgaria Ltd., Energoproject, 15th floor,

51 James Bourchier Blvd., 1407 SOFIA, Tel. +359 2 68 9211, Fax. +359 2 68 9102

Canada: PHILIPS SEMICONDUCTORS/COMPONENTS,

Tel. +1 800 234 7381, Fax. +1 800 943 0087

China/Hong Kong: 501 Hong Kong Industrial Technology Centre,

72 Tat Chee Avenue, Kowloon Tong, HONG KONG, Tel. +852 2319 7888, Fax. +852 2319 7700

Colombia: see South America Czech Republic: see Austria

Denmark: Sydhavnsgade 23, 1780 COPENHAGEN V,

Tel. +45 33 29 3333, Fax. +45 33 29 3905 Finland: Sinikalliontie 3, FIN-02630 ESPOO, Tel. +358 9 615 800, Fax. +358 9 6158 0920

France: 51 Rue Carnot, BP317, 92156 SURESNES Cedex,

Tel. +33 1 4099 6161, Fax. +33 1 4099 6427

Germany: Hammerbrookstraße 69, D-20097 HAMBURG,

Tel. +49 40 2353 60, Fax. +49 40 2353 6300

Hungary: see Austria

India: Philips INDIA Ltd, Band Box Building, 2nd floor, 254-D, Dr. Annie Besant Road, Worli, MUMBAI 400 025,

Tel. +91 22 493 8541, Fax. +91 22 493 0966

Indonesia: PT Philips Development Corporation, Semiconductors Division,

Gedung Philips, Jl. Buncit Raya Kav.99-100, JAKARTA 12510, Tel. +62 21 794 0040 ext. 2501, Fax. +62 21 794 0080

Ireland: Newstead, Clonskeagh, DUBLIN 14, Tel. +353 1 7640 000, Fax. +353 1 7640 200

Israel: RAPAC Electronics, 7 Kehilat Saloniki St, PO Box 18053, TEL AVIV 61180, Tel. +972 3 645 0444, Fax. +972 3 649 1007

Italy: PHILIPS SEMICONDUCTORS, Via Casati, 23 - 20052 MONZA (MI),

Tel. +39 039 203 6838. Fax +39 039 203 6800

Japan: Philips Bldg 13-37, Kohnan 2-chome, Minato-ku, TOKYO 108-8507, Tel. +81 3 3740 5130, Fax. +81 3 3740 5057

Korea: Philips House, 260-199 Itaewon-dong, Yongsan-ku, SEOUL,

Tel. +82 2 709 1412, Fax. +82 2 709 1415

Malaysia: No. 76 Jalan Universiti, 46200 PETALING JAYA, SELANGOR,

Tel. +60 3 750 5214, Fax. +60 3 757 4880

Mexico: 5900 Gateway East, Suite 200, EL PASO, TEXAS 79905,

Tel. +9-5 800 234 7381, Fax +9-5 800 943 0087

Middle East: see Italy

Netherlands: Postbus 90050, 5600 PB EINDHOVEN, Bldg. VB,

Tel. +31 40 27 82785, Fax. +31 40 27 88399

New Zealand: 2 Wagener Place, C.P.O. Box 1041, AUCKLAND,

Tel. +64 9 849 4160, Fax. +64 9 849 7811 Norway: Box 1, Manglerud 0612, OSLO, Tel. +47 22 74 8000, Fax. +47 22 74 8341

Pakistan: see Singapore

Philippines: Philips Semiconductors Philippines Inc., 106 Valero St. Salcedo Village, P.O. Box 2108 MCC, MAKATI, Metro MANILA, Tel. +63 2 816 6380, Fax. +63 2 817 3474

Poland: Al.Jerozolimskie 195 B, 02-222 WARSAW, Tel. +48 22 5710 000, Fax. +48 22 5710 001

Portugal: see Spain

Russia: Philips Russia, UI. Usatcheva 35A, 119048 MOSCOW,

Tel. +7 095 755 6918, Fax. +7 095 755 6919

Singapore: Lorong 1, Toa Payoh, SINGAPORE 319762,

Tel. +65 350 2538, Fax. +65 251 6500

Slovakia: see Austria Slovenia: see Italy

South Africa: S.A. PHILIPS Pty Ltd., 195-215 Main Road Martindale,

2092 JOHANNESBURG, P.O. Box 58088 Newville 2114,

Tel. +27 11 471 5401, Fax. +27 11 471 5398 South America: Al. Vicente Pinzon, 173, 6th floor, 04547-130 SÃO PAULO, SP. Brazil.

Tel. +55 11 821 2333. Fax. +55 11 821 2382 Spain: Balmes 22, 08007 BARCELONA Tel. +34 93 301 6312, Fax. +34 93 301 4107

Sweden: Kottbygatan 7, Akalla, S-16485 STOCKHOLM,

Tel. +46 8 5985 2000, Fax. +46 8 5985 2745

Switzerland: Allmendstrasse 140, CH-8027 ZÜRICH,

Tel. +41 1 488 2741 Fax. +41 1 488 3263

Taiwan: Philips Semiconductors, 6F, No. 96, Chien Kuo N. Rd., Sec. 1, TAIPEI, Taiwan Tel. +886 2 2134 2886, Fax. +886 2 2134 2874

Thailand: PHILIPS ELECTRONICS (THAILAND) Ltd. 209/2 Sanpavuth-Bangna Road Prakanong, BANGKOK 10260,

Tel. +66 2 745 4090, Fax. +66 2 398 0793

Turkey: Yukari Dudullu, Org. San. Blg., 2.Cad. Nr. 28 81260 Umraniye, ISTANBUL, Tel. +90 216 522 1500, Fax. +90 216 522 1813

Ukraine: PHILIPS UKRAINE, 4 Patrice Lumumba str., Building B, Floor 7, 252042 KIEV, Tel. +380 44 264 2776, Fax. +380 44 268 0461

United Kingdom: Philips Semiconductors Ltd., 276 Bath Road, Hayes, MIDDLESEX UB3 5BX, Tel. +44 208 730 5000, Fax. +44 208 754 8421

United States: 811 East Arques Avenue, SUNNYVALE, CA 94088-3409, Tel. +1 800 234 7381, Fax. +1 800 943 0087

Uruguay: see South America Vietnam: see Singapore

Yugoslavia: PHILIPS, Trg N. Pasica 5/v, 11000 BEOGRAD,

Tel. +381 11 3341 299, Fax.+381 11 3342 553

For all other countries apply to: Philips Semiconductors, International Marketing & Sales Communications, Building BE-p, P.O. Box 218, 5600 MD EINDHOVEN, The Netherlands, Fax. +31 40 27 24825

Internet: http://www.semiconductors.philips.com

© Philips Electronics N.V. 2000 All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

403502/03/pp24

Date of release: 2000 Feb 15

Document order number: 9397 750 06724

SCA69

Let's make things better.





